



STPS0540Z / STPS0560Z

SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

I _{F(AV)}	0.5 A
V _{RRM}	40 / 60V
V _F (max)	0.40 / 0.50V

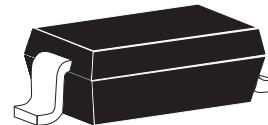
FEATURES AND BENEFITS

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching

DESCRIPTION

Single Schottky rectifier suited for switch mode power supplies and high frequency DC to DC converters.

Packages in SOD-123, these devices are intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications. Due to the small size of the package these devices fit GSM and PCMCIA requirements.



SOD-123

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value		Unit	
		STPS			
		0540Z	0560Z		
V _{RRM}	Repetitive peak reverse voltage	40	60	V	
I _{F(RMS)}	RMS forward current		2	A	
I _{F(AV)}	Average forward current δ=0.5	STPS0540Z STPS0560Z	T _a = 60°C T _a = 40°C	0.5	A
I _{FSM}	Surge non repetitive forward current	tp=10ms sinusoidal		5.5	A
dV/dt	Critical rate of rise of reverse voltage		10000	V/μs	
T _{stg}	Storage temperature range		- 65 to + 150	°C	
T _j	Maximum operating junction temperature *		150	°C	
TL	Maximum temperature for soldering during 10s		260	°C	

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th}(j-a)}$ thermal runaway condition for a diode on its own heatsink

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THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th} (j-a)	Junction to ambient (*)	340	°C/W

(*) Mounted on epoxy board.

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions	Value				Unit	
			STPS0540Z		STPS0560Z			
			typ.	max.	typ.	max.		
I _R *	Reverse leakage current	T _j =25°C	V _R = V _{RRM}		40		50	µA
		T = 100°C		1.5	5	1	4	mA
V _F **	Forward voltage drop	T _j =25°C	I _F = 0.5 A		0.50		0.53	V
		T _j =100°C		0.35	0.40	0.44	0.50	
		T _j =25°C	I _F = 1 A		0.55		0.66	
		T _j =100°C		0.45	0.51	0.58	0.65	

Pulse test : * tp = 5 ms, δ < 2%

** tp = 380 µs, δ < 2%

To evaluate the maximum conduction losses use the following equation :

$$\text{STPS0540Z: } P = 0.29 \times I_{F(AV)} + 0.22 \times I_F^2(\text{RMS})$$

$$\text{STPS0560Z: } P = 0.35 \times I_{F(AV)} + 0.3 \times I_F^2(\text{RMS})$$

Fig. 1-1: Average forward power dissipation versus average forward current.(STPS0540Z)

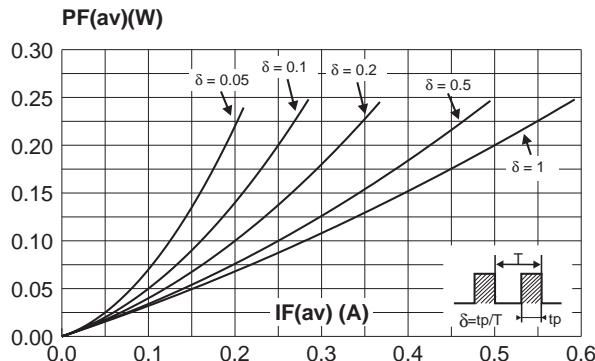


Fig. 1-2: Average forward power dissipation versus average forward current.(STPS0560Z)

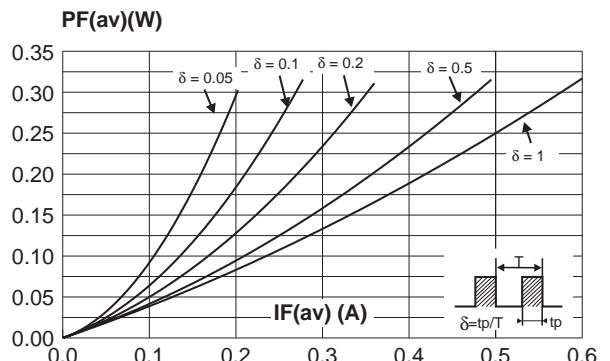


Fig. 2: Average forward current versus ambient temperature ($\delta = 0.5$).

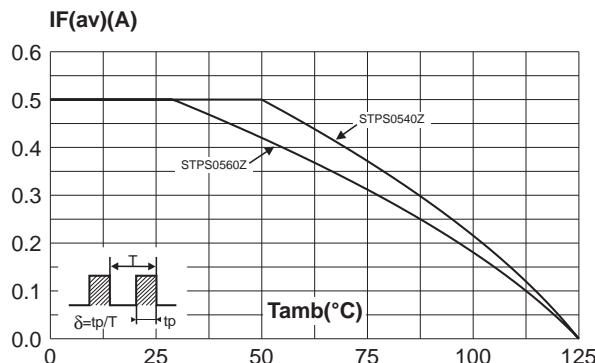


Fig. 3: Non repetitive surge peak forward current versus overload duration (maximum values).

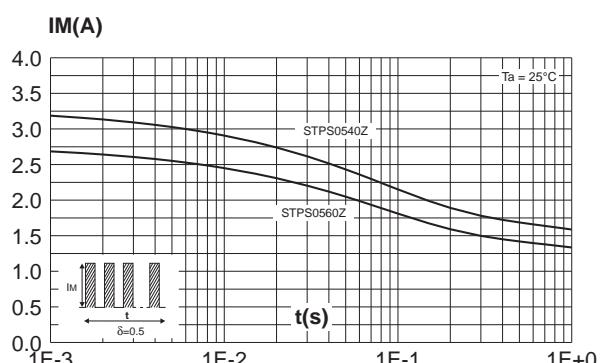


Fig. 4: Relative variation of thermal impedance junction to ambient versus pulse duration (Epoxy printed circuit board FR4 with recommended pad layout).

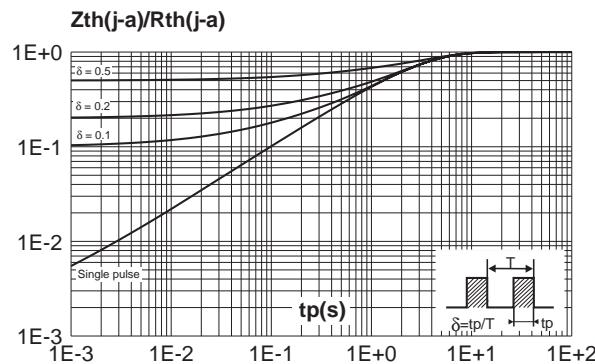
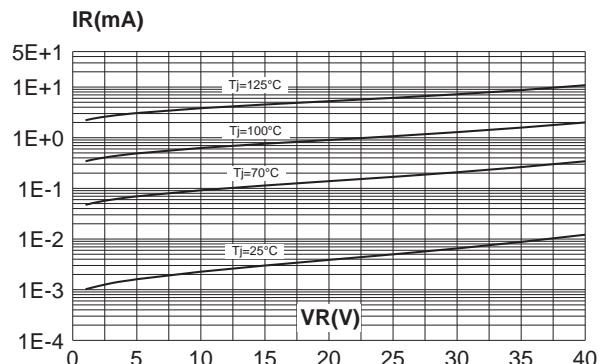


Fig. 5-1: Reverse leakage current versus reverse voltage applied (typical values).(STPS0540Z)



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Fig. 5-2: Reverse leakage current versus reverse voltage applied (typical values).(STPS0560Z)

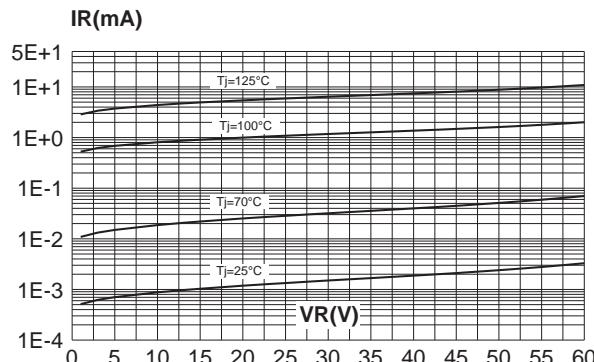


Fig. 7: Junction capacitance versus reverse voltage applied (typical values).

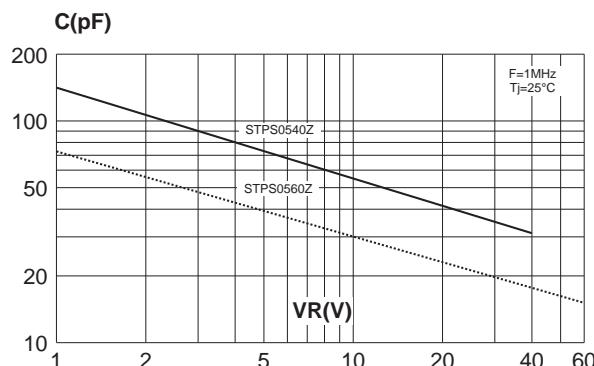


Fig. 8-2: Forward voltage drop versus forward current (maximum values).(STPS0560Z)

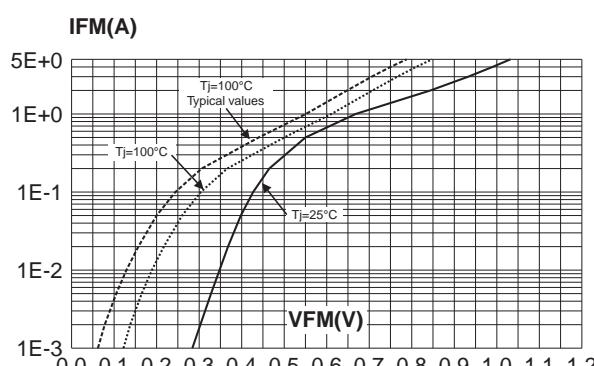


Fig. 6: Reverse leakage current versus junction temperature (typical values).

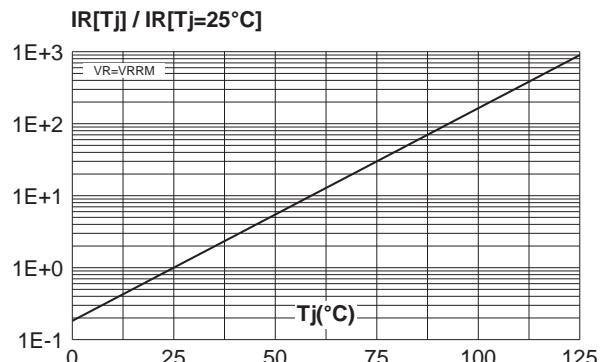


Fig. 8-1: Forward voltage drop versus forward current (maximum values).(STPS0540Z)

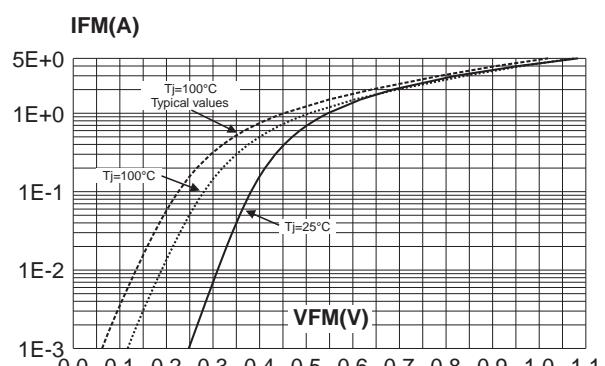
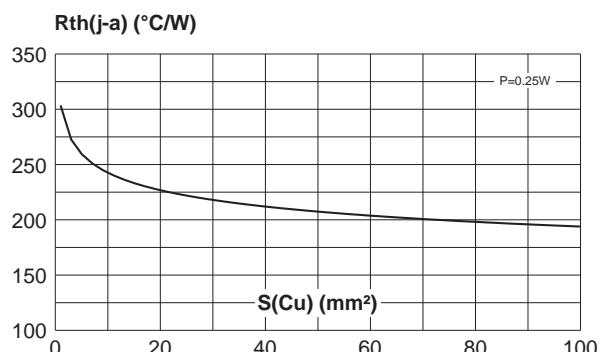


Fig. 9: Variation of thermal resistance junction to ambient versus copper surface under each lead (Printed circuit board FR4, e(Cu) = 35µm).

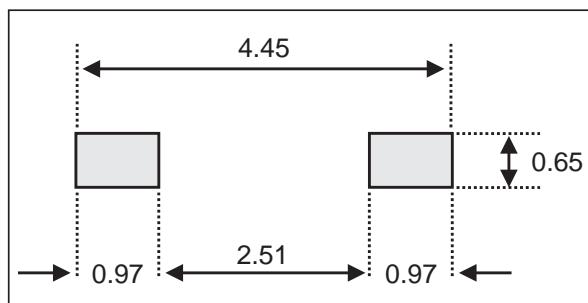


PACKAGE MECHANICAL DATA

SOD-123

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A			1.45	0.057
A1	0	0.1	0	0.004
A2	0.85	1.35	0.033	0.053
b	0.55 Typ.		0.022 Typ.	
c	0.15 Typ.		0.039 Typ.	
D	2.55	2.85	0.1	0.112
E	1.4	1.7	0.055	0.067
G	0.25		0.01	
H	3.55	3.95	0.14	0.156

FOOTPRINT (in millimeters)



MARKING

Type	Marking	Package	Weight	Base qty	Delivery mode
STPS0540Z	Z54	SOD-123	0.01 g	3000	Tape & reel
STPS0560Z	Z56	SOD-123	0.01 g	3000	Tape & reel

- Epoxy meets UL94, V0.
- Band indicates cathode.

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